

Medium Power Phase Control Thyristors (Stud Version), 50 A



PRIMARY CHARACTERISTICS				
I _{T(AV)}	50 A			
V _{DRM} /V _{RRM}	100 V, 200 V, 400 V, 600 V, 800 V, 1000 V, 1200 V			
V _{TM}	1.60 V			
I _{GT}	100 mA			
T _J	-40 °C to 125 °C			
Package	TO-65 (TO-208AC)			
Circuit configuration	Single SCR			

FEATURES

- High current rating
- Excellent dynamic characteristics
- dV/dt = 1000 V/µs option
- · Superior surge capabilities
- Standard package
- · Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- · Phase control applications in converters
- · Lighting circuits
- Battery charges
- Regulated power supplies and temperature and speed control circuit

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		50	А		
I _{T(AV)}	T _C	94	°C		
I _{T(RMS)}		80	A		
I _{TSM}	50 Hz	1430	Α		
	60 Hz	1490			
2t	50 Hz	10.18	1.42-		
1-1	60 Hz	9.30	kA ² s		
V _{DRM} /V _{RRM}		100 to 1200	V		
tq	Typical	110	μs		
TJ		-40 to +125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	$\begin{aligned} I_{DRM}/I_{RRM} & \text{MAXIMUM AT} \\ & T_J = T_J & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$			
	10	100	150				
	20	200	300				
	40	400	500				
VS-50RIA	60	600	700	15			
	80	800	900				
	100	1000	1100				
	120	1200	1300				

Notes

Revision: 21-Sep-17 **1** Document Number: 93711

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/µs

⁽²⁾ For voltage pulses with $t_p \le 5$ ms



PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current		100% oinusoi	4000 de callel carel alle		50	Α
at case temperature	I _{T(AV)}	180° sinusoidal conduction		94	°C	
Maximum RMS on-state current	I _{T(RMS)}				80	Α
Maximum peak, one-cycle		t = 10 ms	No voltage		1430	
		t = 8.3 ms	reapplied		1490	_
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		1200	A
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1255	
Maximum I ² t for fusing		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	10.18	- kA ² s
	l ² t	t = 8.3 ms	reapplied		9.30	
		t = 10 ms	100 % V _{RRM} reapplied		7.20	
		t = 8.3 ms			6.56	
Maximum I ² √t for fusing	I ² √t	$t = 0.1$ to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		101.8	kA²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum		0.94	V	
High level value of threshold voltage	V _{T(TO)2}	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.08	V	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum		4.08	mΩ	
High level value of on-state slope resistance	r _{t2}	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		3.34	11152	
Maximum on-state voltage	V _{TM}	I _{pk} = 157 A, T _J = 25 °C		1.60	V	
Maximum holding current	I _H	$T_J = 25$ °C, anode supply 22 V, resistive load, initial $I_T = 2$ A		200	mA	
Latching current	Ι _L	Anode supp	Anode supply 6 V, resistive load		400	1

SWITCHING						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum rate of	$V_{DRM} \le 600 \text{ V}$	dl/dt	T_{C} = 125 °C, V_{DM} = Rated $V_{DRM},$ Gate pulse = 20 V, 15 $\Omega,$ t_{p} = 6 $\mu s,$ t_{r} = 0.1 μs maximum I_{TM} = (2 x rated dl/dt) A	200	- A/μs	
rise of turned-on current	$V_{DRM} \leq 1600 \; V$	di/dt		100		
Typical delay time		$t_{\rm d}$ $T_{\rm C}$ = 25 °C, $V_{\rm DM}$ = Rated $V_{\rm DRM}$, $I_{\rm TM}$ = 10 A dc resistive circuit Gate pulse = 10 V, 15 Ω source, $t_{\rm p}$ = 20 μs		0.9		
Typical turn-off time		tq	T_C = 125 °C, I_{TM} = 50 A, reapplied dV/dt = 20 V/ μ s dIr/dt = -10 A/ μ s, V_R = 50 V	110	μs	

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise of dV/dt		$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	200	V/µs	
off-state voltage	uv/ut	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	500 (1)	ν/μ5	

Note

 $^{^{(1)}}$ Available with dV/dt = 1000 V/ μs , to complete code add S90 i.e. 50RIA120S90



TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum, $t_p \le \xi$	5 ms	10	w
Maximum average gate power	P _{G(AV)}			2.5	VV
Maximum peak positive gate current	I _{GM}			2.5	А
Maximum peak positive gate voltage	+V _{GM}			20	V
Maximum peak negative gate voltage	-V _{GM}				\ \ \
	I _{GT}	T _J = - 40 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V	250	mA
DC gate current required to trigger		T _J = 25 °C		100	
		T _J = 125 °C		50	
	.,,	T _J = - 40 °C	anode to cathode applied	3.5	V
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C		2.5	
DC gate current not to trigger	I _{GD}	T _J = T _J maximum, V _{DRM} = Rated voltage	Maximum gate current/voltage not to trigger is the maximum	5.0	mA
DC gate voltage not to trigger	V_{GD}	$T_J = T_J$ maximum	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.35	K/W	
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, flat and greased			
Allowable mounting torque		Non-lubricated threads	3.4 + 0 - 10 % (30)	N · m	
Allowable mounting torque		Lubricated threads	2.3 + 0 - 10 % (20)	(lbf·in)	
Approximate weight			28	g	
Approximate weight			1.0	OZ.	
Case style		See dimensions - link at the end of datasheet TO-65 (TO-208AC)		208AC)	

△R _{thJC} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.078	0.057					
120°	0.094	0.098					
90°	0.120	0.130	$T_J = T_J$ maximum	K/W			
60°	0.176	0.183					
30°	0.294	0.296					

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

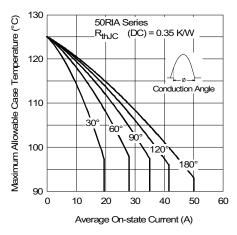


Fig. 1 - Current Ratings Characteristics

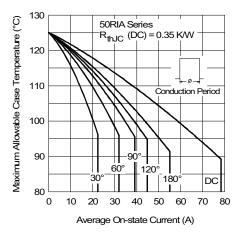


Fig. 2 - Current Ratings Characteristics

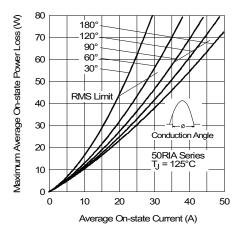


Fig. 3 - On-State Power Loss Characteristics

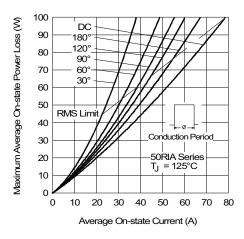


Fig. 4 - On-State Power Loss Characteristics

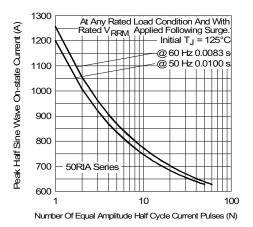


Fig. 5 - Maximum Non-Repetitive Surge Current

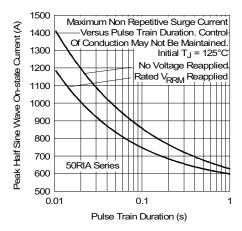


Fig. 6 - Maximum Non-Repetitive Surge Current



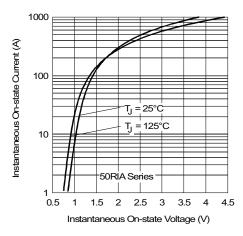


Fig. 7 - Forward Voltage Drop Characteristics

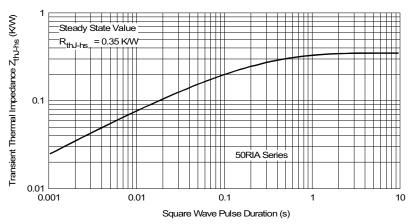


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

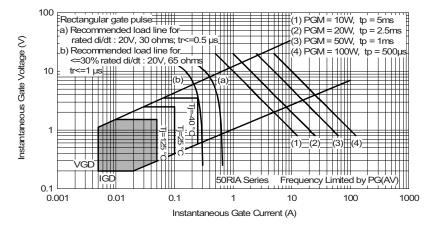
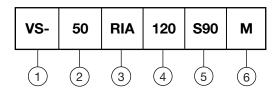


Fig. 9 - Gate Characteristics



ORDERING INFORMATION TABLE

Device code



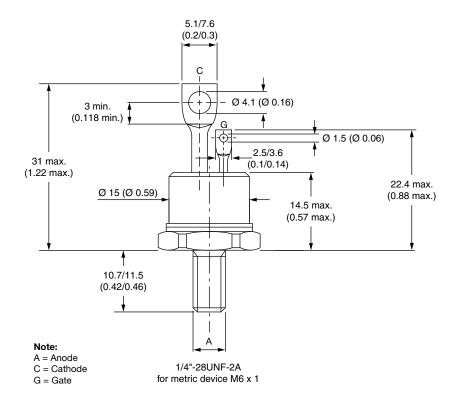
- 1 Vishay Semiconductors product
- 2 Current code
- 3 Essential part number
- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 5 Critical dV/dt:
 - None = 500 V/µs (standard value)
 - S90 = 1000 V/µs (special selection)
- 6 • None = stud base TO-65 (TO-208AC) 1/4" 28UNF-2A
 - M = stud base TO-65 (TO-208AC) M6 x 1

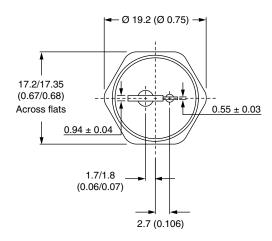
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95334			



TO-208AC (TO-65)

DIMENSIONS in millimeters (inches)





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